



Features

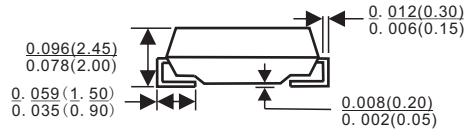
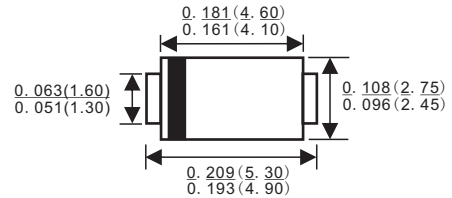
- ✧ For surface mounted application
- ✧ Glass passivated junction chip.
- ✧ Low forward voltage drop
- ✧ High current capability
- ✧ Easy pick and place
- ✧ High surge current capability
- ✧ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ✧ High temperature soldering: 260°C / 10 seconds at terminals

Mechanical Data

- ✧ Case: Molded plastic
- ✧ Polarity: Indicated by cathode band
- ✧ Packaging: 12mm tape
- ✧ Weight: 0.064 gram

Marking Information

SMA/DO-214AC



LGE: Lu Guang Electronic
XXXX: marking code (S1A-S1Y)

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

Type Number	Symbol	S1A	S1B	S1D	S1G	S1J	S1K	S1M	S1T	S1W	S1X	S1Y	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	1300	1600	1800	2000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	760	780	840	900	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	1300	1600	1800	2000	V
Maximum Average Forward Rectified Current @ $T_L = 110^\circ\text{C}$	$I_{(AV)}$	1.0											A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30											A
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.1											V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	I_R	1.0											μA
Typical Reverse Recovery Time (Note 1)	T_{rr}	1.5											μs
Typical Junction Capacitance (Note 2)	C_j	12											pF
Non-Repetitive Peak Reverse Avalanche Energy at 25°C, $I_{AS}=1\text{A}$, $L=10\text{mH}$	E_{AS}	5											mJ
Typical Thermal Resistance (Note 3)	$R_{\theta JL}$ $R_{\theta JA}$	27 75					30 85					$^\circ\text{C/W}$	
Operating Temperature Range	T_J	-55 to +150											$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150											$^\circ\text{C}$

- Notes:
- Reverse Recovery Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
 - Measured at 1 MHz and Applied $V_R=4.0$ Volts
 - Measured on P.C. Board with 0.2" x 0.2" (5.0mm x 5.0mm) Copper Pad Areas.

RATINGS AND CHARACTERISTIC CURVES (S1A THRU S1M)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

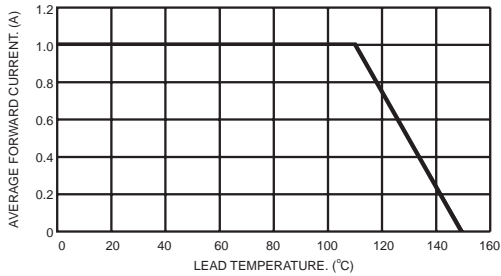


FIG.2- TYPICAL REVERSE CHARACTERISTICS

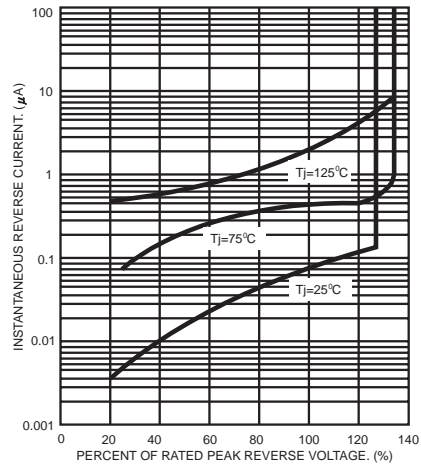


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

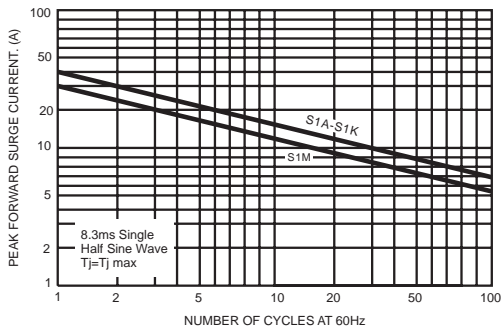


FIG.5- TYPICAL FORWARD CHARACTERISTICS

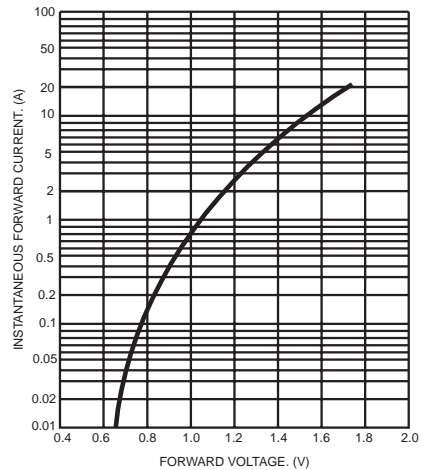


FIG.4- TYPICAL JUNCTION CAPACITANCE

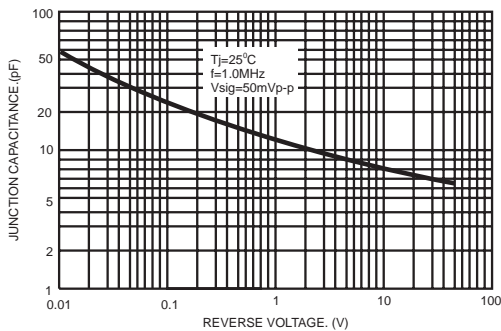
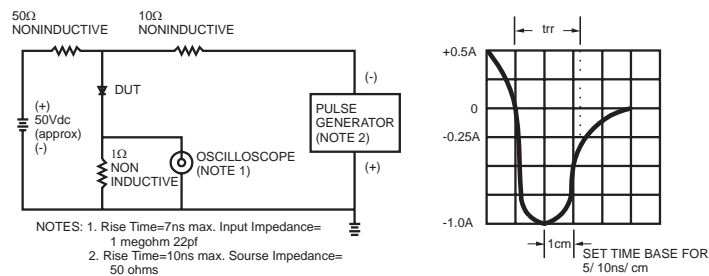


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



PACKAGE	SPQ/PCS	CARTON SPQ/PCS	CARTON SIZE/CM	CARTON GW/KG	CARTON NW/KG
SMA	5000/REEL	80000	36X30.6X31	12.00	11.00